NSN 5961-00-247-7915

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View Online at https://aerobasegroup.com/nsn/5961-00-247-7915 **Inclosure Material:** Metal **Overall Length:** 0.475 inches **Overall Diameter:** 0.544 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-48 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 840.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 16.00 amperes forward current, average absolute and 150.00 amperes source cutoff current absolute **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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